

IPOSIM Lifetime Calculation Report

Report No: 51d2d008-b820-4628-b72d-79753e9fd13a

2021-11-19

User	Customer
	Infineon Technologies AG

Summary

Lifetime calculation for: FF1200R17IP5

Topology: DC/AC Three Phase - 2 Level

Load cycle duration: 1:47:28 [h:min:s]

Analysis mode: Single cycle simulation

Cooling: User defined heatsink

Max. junction temperature: 168.7 °C (Diode)

Estimated lifetime: 3265 possible cycles

Lifetime limititation : Diode - Power cycling

User comments

test_6k5Points

Calculation status message

Calculation finished normally



Contents

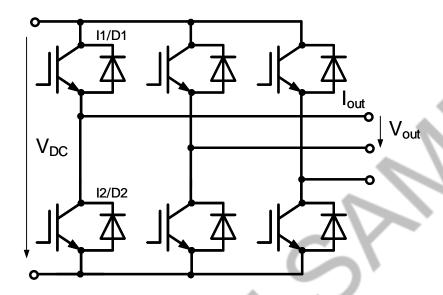
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1 Simulation Conditions

1.1 Simulation Parameters

Selected topology: DC/AC Three Phase - 2 Level



Control algorithm: Sine-Triangle PWM Load type: Lagging (inductive)

1.2 Application Parameters

 $R_{g,on}$: 0.6 \blacksquare 1.0 \blacksquare

1.3 Cooling Conditions

Ambient temperature: 40 ℃ Heatsink thermal model:

i	1	2	3	4	5
R _{th,hs,i} [K/W]	0.0824	0	0	0	0
$ au_{th,hs,i}$ [s]	70	1	1	1	1



1.4 Selected Device

FF1200R17IP5

Voltage class: 1 700 V Current rating: 1 200 A

Package: PrimePACK2

IGBT Parameters

 $V_{ce,sat}$:2.14 V (at 1 200 A, 125 °C) E_{on} :0.3995 J (at 1 200 A, 125 °C) E_{off} :0.3984 J (at 1 200 A, 125 °C)

 $R_{th,JH}$: 0.024 K/W $T_{vi,max}$: 175 °C

Diode Parameters

 V_f : 1.74 V (at 1 200 A, 125 °C) E_{rec} : 0.244 J (at 1 200 A, 125 °C)

 $R_{th,JH}$: 0.044 K/W $T_{vj,max}$: 175 °C

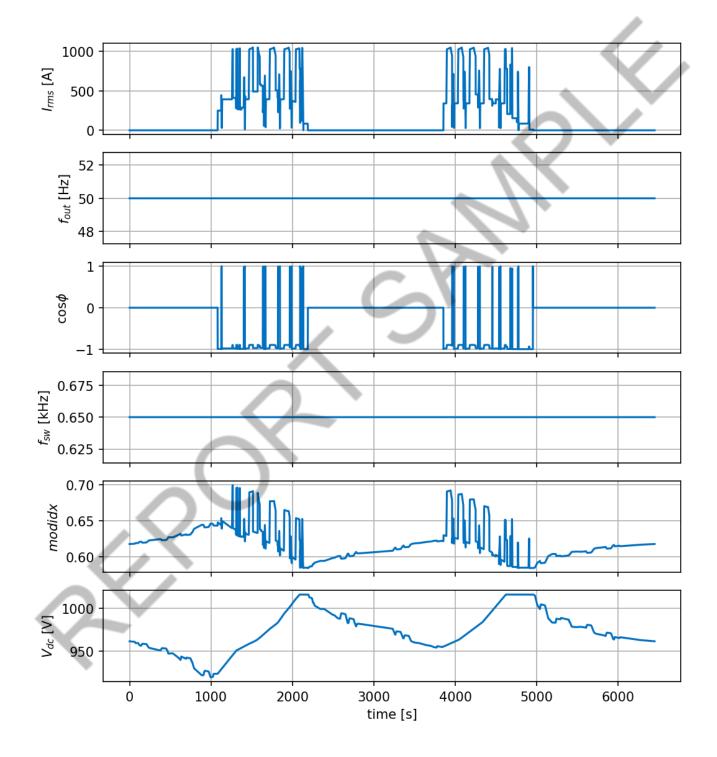
Product website: https://www.infineon.com/



1.5 Load Cycle Profile

Load cycle duration: 1:47:28 [h:min:s]

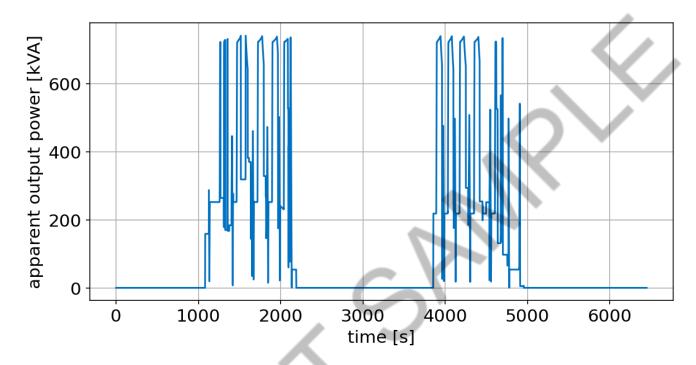
Interpolation: Yes



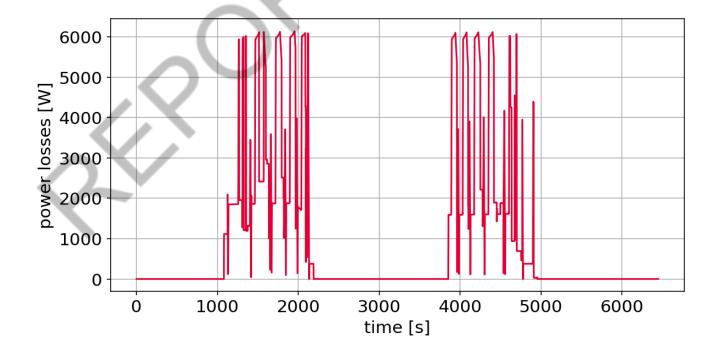


2 Simulation Results

Converter Output Power

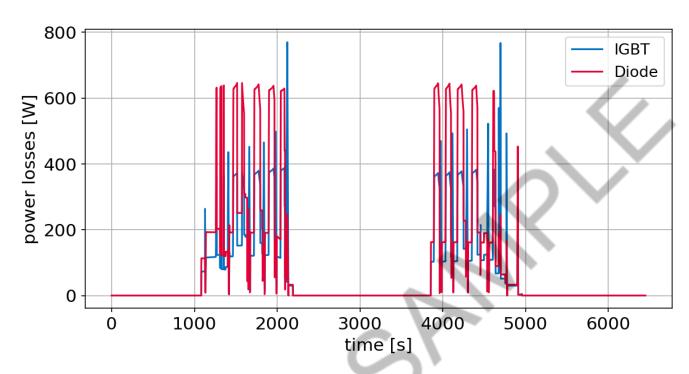


Converter Power Losses



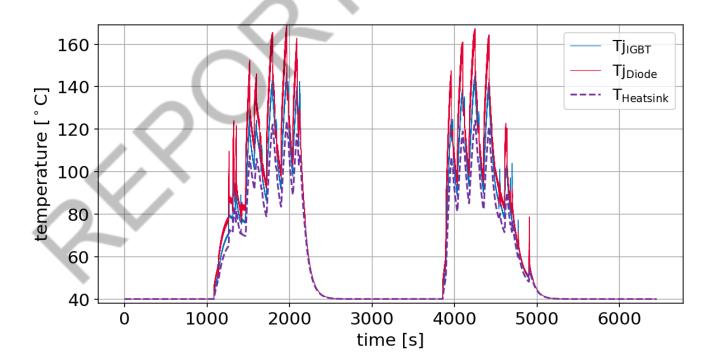


Device Power Losses



Temperature Results

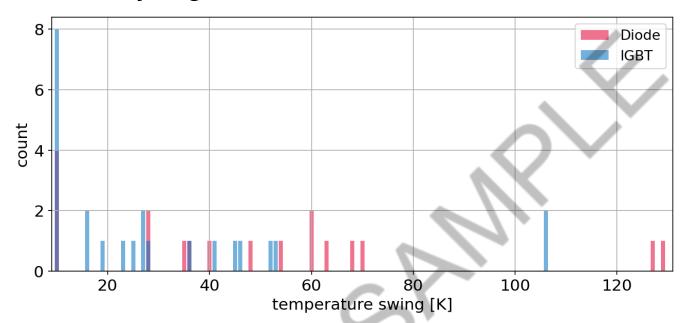
Ambient temperature: 40 ℃



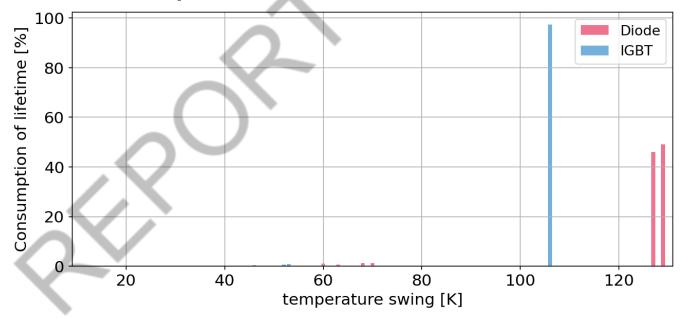


3 Lifetime Calculation

3.1 Power Cycling of IGBT and Diode



Lifetime Consumption



Estimated power cycling lifetime for IGBT: **10858** cycles Estimated power cycling lifetime for Diode: **3265** cycles



3.2 Summary of Lifetime Calculation

Power cyclin		Power cycling	Thermal
	IGBT	Diode	cycling
Possible number of cycles	10858	3265	n/a

Total lifetime: 3265 cycles

Lifetime limitation: **Diode - Power cycling**

Notes:

- Thermal cycling is not calculated for certain types of modules, e.g. baseplate-less modules, or if a fixed heatsink temperature is selected as cooling condition.



References

- [1] AN2019-05 PC and TC Diagrams
- [2] Product Parameters: Datasheet FF1200R17IP5
- [3] Product Website: https://www.infineon.com/
- [4] Power Cycling Reference: (PC-15) Power Cycling IGBT5 rev.2
- [5] Thermal Cycling Reference: n/a

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